NSN 5961-01-363-4677

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-363-4677 **Inclosure Material:** Metal **Overall Length:** Between 0.028 inches and 0.034 inches Overall Diameter: 0.360 inches **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 45.0 repetitive peak reverse voltage, peak total value all semiconductor device diode and 45.0 working peak reverse voltage, peak total value all semiconductor device diode and 54.0 nonrepetitive peak reverse voltage all semiconductor device diode **Current Rating Per Characteristic:** 80.00 amperes forward current, average preset all semiconductor device diode and 6.00 amperes forward current, average all semiconductor device diode **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius ambient air **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0